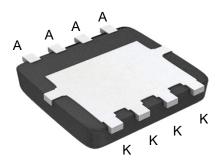




## **Schoktty Barrier Diode**

#### **Feature**

- > Negligible reverse recovery
- ➤ Positive Temperature Coefficient
- > Temperature-Independent Switching
- > Fast switching
- > Pb-free / RoHS compliant
- ➤ Low switching loss
- ➤ Higher frequency
- > Low heat dissipation requirements
- > Reduce size and cost of the system
- ➤ High-reliability



DFN5060-8L Bottom View

### **Applications**

- Power inverters
- Uninterruptable power supplies
- ➤ High performance SMPS
- ➤ Power Factor Correction



**Circuit Diagram** 

## Absolute maximum rating@25°C

Parameter			Value	Units
Repetitive Peak Reverse Voltage			650	V
Surge Peak Reverse Voltage			650	\ \
DC Peak Reverse Voltage	$V_R$	650	V	
	T <sub>c</sub> =25℃		23	A
Continuous Forward Current	T <sub>c</sub> =135°C	I <sub>F</sub>	12	
	T <sub>c</sub> =162°C		6.0	
Repetitive Peak Forward Surge Current	T <sub>c</sub> =25°C,t <sub>p</sub> =10ms,Half Sine Pulse		28	А
	T <sub>c</sub> =110°C,t <sub>p</sub> =10ms,Half Sine Pulse	I <sub>FRM</sub>	17	
Non-repetitive Forward Surge Current	T <sub>c</sub> =25°C,t <sub>p</sub> =10ms,Half Sine Pulse	,	48	А
	T <sub>c</sub> =110°C,t <sub>p</sub> =10ms,Half Sine Pulse	l <sub>FSM</sub>	43	
i²t Value	T <sub>c</sub> =25°C,t <sub>p</sub> =10ms	∫i² dt	11.4	A <sup>2</sup> s
	T <sub>c</sub> =110°C,t <sub>p</sub> =10ms	ן ווי מנ	9.1	
Power Dissipation	T <sub>c</sub> =25°C	Б	71	W
	T <sub>c</sub> =110°C	P <sub>tot</sub>	30	
Operating Junction Range	T <sub>J</sub>	-55~+175	°C	
Storage Temperature Range	T <sub>STG</sub>	-55~+150	°C	

# Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
Compard Voltage	V <sub>F</sub>	I <sub>F</sub> = 6A, T <sub>J</sub> =25°C	-	1.3	1.5	V	
Forward Voltage		I <sub>F</sub> = 6A, T <sub>J</sub> =175°C	-	1.5	-		
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 650V, T <sub>J</sub> =25°C	-	-	50	μΑ	
		V <sub>R</sub> = 650V, T <sub>J</sub> =175°C	-	-	200		
Total Capacitive Charge	Q <sub>C</sub>	V <sub>R</sub> = 400V	-	18	-	nC	
	С	$V_R = 0V, f = 1MHz$	-	358	-		
Total Capacitance		V <sub>R</sub> = 200V,f = 1MHz	-	36	-	pF	
		V <sub>R</sub> = 400V,f = 1MHz	-	30	-		

#### **Thermal Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units
Thermal Resistance (Junction to case)	$R_{ heta JC}$	-	2.10	-	°C/W

## Typical Characteristics

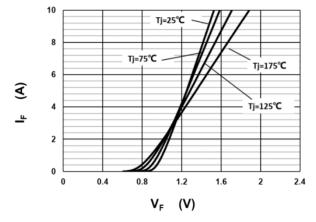


Fig.1 Forward Characteristics

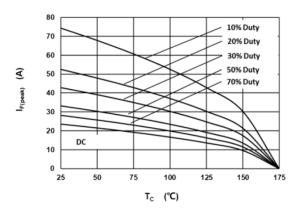


Fig.3 Current Derating

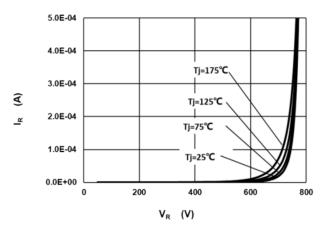


Fig.2 Reverse Characteristics

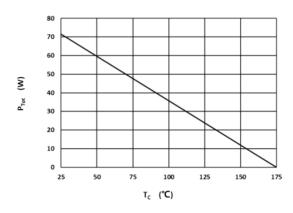


Fig.4 Power Derating

# **Schoktty Barrier Diode**

## PSICS8N650V6N

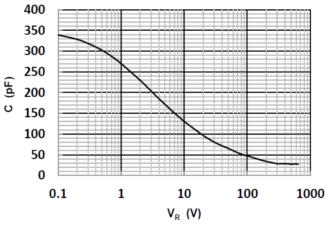


Fig.5 Capacitance vs. Reverse Voltage

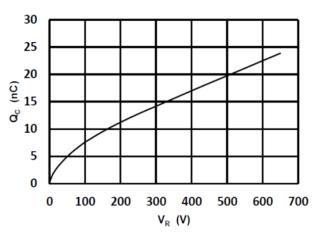


Fig.6 Reverse Charge vs. Reverse Voltage

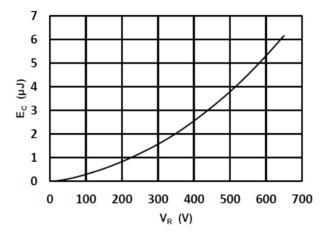


Fig.7 Capacitance Stored Energy

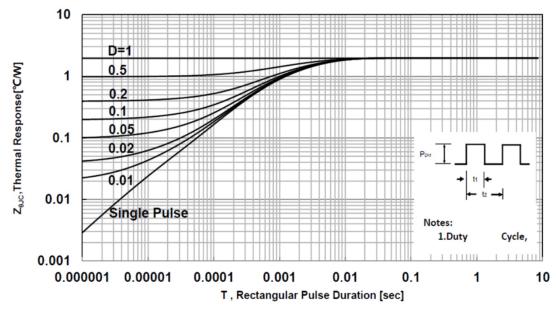
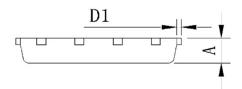
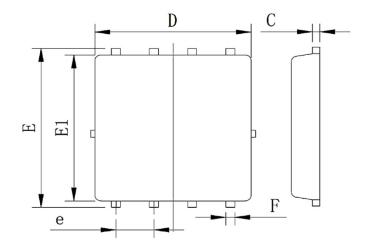
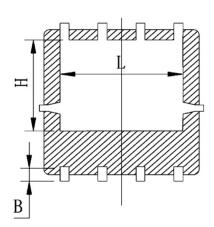


Fig.8 Transient Thermal Impedance

# Product Dimension (DFN5060-8L)







Dim	Millimeters		Inches		
Dim	Min	Max	Min	Max	
Α	0.90	1.00	0.035	0.039	
В	0.48	0.68	0.019	0.027	
С	0.20	0.30	0.008	0.012	
D	5.00	5.40	0.197	0.213	
D1	-	0.15	-	0.006	
Е	5.90	6.20	0.232	0.244	
E1	5.40	5.70	0.213	0.224	
е	1.22	1.32	0.048	0.052	
F	0.25	0.35	0.010	0.014	
Н	3.27	3.67	0.129	0.144	
L	3.80	4.20	0.150	0.165	

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